

# MOTOROLA SEMICONDUCTOR TECHNICAL DATA

## MONOLITHIC OPERATIONAL AMPLIFIER

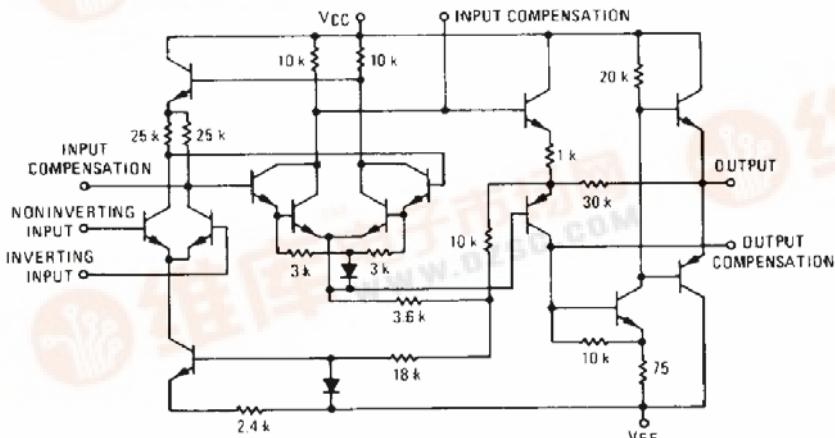
... designed for use as a summing amplifier, integrator, or amplifier with operating characteristics as a function of the external feedback components.

- High-Performance Open Loop Gain Characteristics  
 $A_{vo} = 45,000$  typical
- Low Temperature Drift –  $\pm 3.0 \mu V/\text{°C}$  typical (MC1709)
- Large Output Voltage Swing –  $\pm 14 \text{ V}$  typical @  $\pm 15 \text{ V}$  Supply
- Low Output Impedance –  $z_o = 150 \text{ ohms}$  typical

## MAXIMUM RATINGS ( $T_A = +25^\circ\text{C}$ unless otherwise noted.)

| Rating                                       | Symbol                             | Value                          | Unit        |
|--|------------------------------------|--------------------------------|-------------|
| Power Supply Voltage                         | V <sub>CC</sub><br>V <sub>EE</sub> | + 18<br>- 18                   | Vdc         |
| Input Differential Voltage Range             | V <sub>IDR</sub>                   | $\pm 5.0$                      | Volts       |
| Input Common-Mode Range                      | V <sub>ICR</sub>                   | $\pm 10$                       | Volts       |
| Output Load Current                          | I <sub>L</sub>                     | 10                             | mA          |
| Output Short-Circuit Duration                | t <sub>S</sub>                     | 5.0                            | s           |
| Power Dissipation (Package Limitation)       | PD                                 |                                |             |
| Metal Can                                    |                                    | 680<br>4.6                     | mW<br>mW/°C |
| Derate above $T_A = +25^\circ\text{C}$       |                                    | 625<br>5.0                     | mW<br>mW/°C |
| Plastic Dual In-Line Packages (MC1709C only) |                                    | 750<br>6.0                     | mW<br>mW/°C |
| Ceramic Dual In-Line Package                 |                                    |                                |             |
| Derate above $T_A = +25^\circ\text{C}$       |                                    |                                |             |
| Operating Ambient Temperature Range          | MC1709A, MC1709<br>MC1709C         | T <sub>A</sub><br>0 to +70     | °C          |
| Storage Temperature Range                    | T <sub>stg</sub>                   | - 65 to + 150<br>- 55 to + 125 | °C          |
| Metal and Ceramic Packages                   |                                    |                                |             |
| Plastic Packages                             |                                    |                                |             |

FIGURE 1 – EQUIVALENT CIRCUIT SCHEMATIC

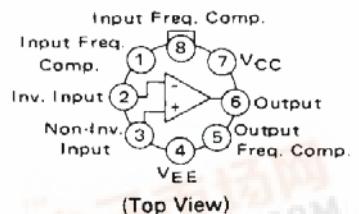


## MC1709 MC1709A MC1709C

## OPERATIONAL AMPLIFIER

### SILICON MONOLITHIC INTEGRATED CIRCUIT

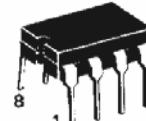
#### PIN CONNECTIONS



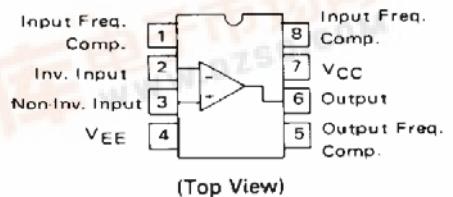
G SUFFIX  
METAL PACKAGE  
CASE 601



P1 SUFFIX  
PLASTIC PACKAGE  
CASE 626  
(MC1709C Only)



U SUFFIX  
CERAMIC PACKAGE  
CASE 693



#### ORDERING INFORMATION

| Device     | Temperature Range | Package     |
|------------|-------------------|-------------|
| MC1709CG   | 0°C to + 70°C     | Metal Can   |
| MC1709CU   |                   | Ceramic DIP |
| MC1709CP1  |                   | Plastic DIP |
| MC1709G,AG | - 55°C to + 125°C | Metal Can   |
| MC1709AU   |                   | Ceramic DIP |

# MC1709, MC1709A, MC1709C

**ELECTRICAL CHARACTERISTICS** (unless otherwise noted,  $+9.0 \text{ V} \leq V_{CC} \leq 15 \text{ V}$ ,  $-9.0 \text{ V} \geq V_{EE} \geq -15 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ )

| Characteristic   | Symbol          | MC1709A |     |     | MC1709 |     |     | Unit          |
|--|-----------------|---------|-----|-----|--------|-----|-----|---------------|
|  |                 | Min     | Typ | Max | Min    | Typ | Max |               |
| Input Offset Voltage<br>( $R_S \leq 10 \text{ k}\Omega$ )                                  | $V_{IO}$        | —       | 0.6 | 2.0 | —      | 1.0 | 5.0 | mV            |
| Input Offset Current   | $I_{IO}$        | —       | 10  | 50  | —      | 50  | 200 | nA            |
| Input Bias Current   | $I_{IB}$        | —       | 100 | 200 | —      | 200 | 500 | nA            |
| Input Resistance   | $r_i$           | 350     | 700 | —   | 150    | 400 | —   | k $\Omega$    |
| Output Resistance  | $r_o$           | —       | 150 | —   | —      | 150 | —   | $\Omega$      |
| Power Supply Currents<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ )            | $I_{CC}/I_{EE}$ | —       | 2.5 | 3.6 | —      | —   | —   | mA            |
| Power Consumption<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ )                | $P_C$           | —       | 75  | 108 | —      | 80  | 165 | mW            |
| Transient Response<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ ). See Figure 8 |                 |         |     |     |        |     |     |               |
| Risetime   | $t_{TLH}$       | —       | —   | 1.5 | —      | 0.3 | 1.0 | $\mu\text{s}$ |
| Overshoot  | OS              | —       | —   | 30  | —      | 10  | 30  | %             |

**ELECTRICAL CHARACTERISTICS** (unless otherwise noted,  $+9.0 \text{ V} \leq V_{CC} \leq 15 \text{ V}$ ,  $-9.0 \text{ V} \geq V_{EE} \geq -15 \text{ V}$ ,  $T_A = -55^\circ\text{C}$  to  $+125^\circ\text{C}$ )

| Characteristic   | Symbol                   | MC1709A              |                      |     | MC1709               |                      |      | Unit                         |
|--|--------------------------|----------------------|----------------------|-----|----------------------|----------------------|------|------------------------------|
|  |                          | Min                  | Typ                  | Max | Min                  | Typ                  | Max  |                              |
| Input Offset Voltage<br>( $R_S \leq 10 \text{ k}\Omega$ )  | $V_{IO}$                 | —                    | —                    | 3.0 | —                    | —                    | 6.0  | mV                           |
| Average Temperature Coefficient of Input Offset Voltage<br>( $R_S = 50 \text{ }\Omega$ , $T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$ )         | $\Delta V_{IO}/\Delta T$ | —                    | 1.8                  | 10  | —                    | —                    | —    | $\mu\text{V}/^\circ\text{C}$ |
| ( $R_S = 50 \text{ }\Omega$ , $T_A = -55^\circ\text{C}$ to $25^\circ\text{C}$ )  |                          | —                    | 1.8                  | 10  | —                    | —                    | —    |                              |
| ( $R_S = 50 \text{ }\Omega$ , $T_A = -55^\circ\text{C}$ to $125^\circ\text{C}$ )   |                          | —                    | —                    | —   | —                    | 3.0                  | —    |                              |
| ( $R_S = 10 \text{ k}\Omega$ , $T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$ )   |                          | —                    | 2.0                  | 15  | —                    | —                    | —    |                              |
| ( $R_S = 10 \text{ k}\Omega$ , $T_A = -55^\circ\text{C}$ to $25^\circ\text{C}$ )   |                          | —                    | 4.8                  | 25  | —                    | —                    | —    |                              |
| ( $R_S = 10 \text{ k}\Omega$ , $T_A = -55^\circ\text{C}$ to $125^\circ\text{C}$ )  |                          | —                    | —                    | —   | —                    | 6.0                  | —    |                              |
| Input Offset Current<br>( $T_A = -55^\circ\text{C}$ )  | $I_{IO}$                 | —                    | 40                   | 250 | —                    | 100                  | 500  | nA                           |
| ( $T_A = 125^\circ\text{C}$ )  |                          | —                    | 3.5                  | 50  | —                    | 20                   | 200  |                              |
| Average Temperature Coefficient of Input Offset Current<br>( $T_A = -55^\circ\text{C}$ to $25^\circ\text{C}$ )                                     | $\Delta I_{IO}/\Delta T$ | —                    | 0.45                 | 2.8 | —                    | —                    | —    | $\text{nA}/^\circ\text{C}$   |
| ( $T_A = 25^\circ\text{C}$ to $125^\circ\text{C}$ )  |                          | —                    | 0.08                 | 0.5 | —                    | —                    | —    |                              |
| Input Bias Current<br>( $T_A = -55^\circ\text{C}$ )  | $I_{IB}$                 | —                    | 300                  | 600 | —                    | 500                  | 1500 | nA                           |
| Input Resistance<br>( $T_A = -55^\circ\text{C}$ )  | $r_i$                    | 85                   | 170                  | —   | 40                   | 100                  | —    | k $\Omega$                   |
| Input Common-Mode Voltage Range<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ )  | $V_{ICR}$                | $\pm 8.0$            | $\pm 10$             | —   | $\pm 8.0$            | $\pm 10$             | —    | V                            |
| Common Mode Rejection Ratio<br>( $R_S \leq 10 \text{ k}\Omega$ )   | CMRR                     | 80                   | 110                  | --  | 70                   | 90                   | —    | dB                           |
| Supply Voltage Rejection Ratio<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ , $R_S \leq 10 \text{ k}\Omega$ )                           | PSRR                     | —                    | 40                   | 100 | —                    | 25                   | 150  | $\mu\text{V/V}$              |
| Large Signal Voltage Gain<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ , $R_L \geq 2.0 \text{ k}\Omega$ ,<br>$V_O = \pm 15 \text{ V}$ ) | $A_V$                    | 25                   | 45                   | 70  | 25                   | 45                   | 70   | V/mV                         |
| Output Voltage Range<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ )   | $V_{OR}$                 | $\pm 12$<br>$\pm 10$ | $\pm 14$<br>$\pm 13$ | —   | $\pm 12$<br>$\pm 10$ | $\pm 14$<br>$\pm 13$ | —    | V                            |
| ( $R_L \geq 10 \text{ k}\Omega$ )  |                          |                      |                      |     |                      |                      |      |                              |
| ( $R_L \geq 2.0 \text{ k}\Omega$ )   |                          |                      |                      |     |                      |                      |      |                              |
| Power Supply Currents<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ )  | $I_{CC}/I_{EE}$          | —                    | 2.7                  | 4.5 | —                    | —                    | —    | mA                           |
| ( $T_A = -55^\circ\text{C}$ )  |                          | —                    | 2.1                  | 3.0 | —                    | —                    | —    |                              |
| ( $T_A = 125^\circ\text{C}$ )  |                          | —                    | —                    | —   | —                    | —                    | —    |                              |
| Power Consumption<br>( $V_{CC} = 15 \text{ V}$ , $V_{EE} = -15 \text{ V}$ )  | $P_C$                    | —                    | 81                   | 135 | —                    | —                    | —    | mW                           |
| ( $T_A = -55^\circ\text{C}$ )  |                          | —                    | 63                   | 90  | —                    | —                    | —    |                              |
| ( $T_A = 125^\circ\text{C}$ )  |                          | —                    | —                    | —   | —                    | —                    | —    |                              |

# MC1709, MC1709A, MC1709C

**ELECTRICAL CHARACTERISTICS** (unless otherwise noted,  $V_{CC} = +15\text{ V}$ ,  $V_{EE} = -15\text{ V}$ ,  $T_A = 25^\circ\text{C}$ )

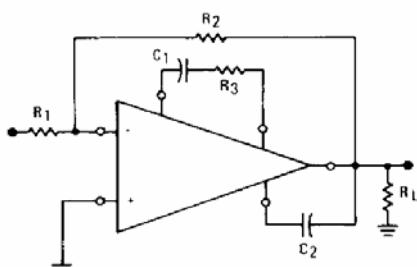
| Characteristic   | Symbol    | MC1709C              |                      |      | Unit            |
|--|-----------|----------------------|----------------------|------|-----------------|
|  |           | Min                  | Typ                  | Max  |                 |
| Input Offset Voltage<br>( $R_S \leq 10\text{ k}\Omega$ , $9.0\text{ V} \leq V_{CC} \leq 15\text{ V}$ , $-9.0\text{ V} \geq V_{EE} \geq -15\text{ V}$ ) | $V_{IO}$  | —                    | 2.0                  | 7.5  | mV              |
| Input Offset Current   | $I_{IO}$  | —                    | 100                  | 500  | nA              |
| Input Bias Current   | $I_{IB}$  | —                    | 300                  | 1500 | nA              |
| Input Resistance   | $r_i$     | 50                   | 250                  | —    | k $\Omega$      |
| Output Resistance  | $r_o$     | —                    | 150                  | —    | $\Omega$        |
| Power Consumption  | $P_C$     | —                    | 80                   | 200  | mW              |
| Large Signal Voltage Gain<br>( $R_L \geq 2.0\text{ k}\Omega$ , $V_O = \pm 10\text{ V}$ )   | $A_V$     | 15                   | 45                   | —    | V/mV            |
| Output Voltage Range<br>( $R_L \geq 10\text{ k}\Omega$ )<br>( $R_L \geq 2.0\text{ k}\Omega$ )  | $V_{OR}$  | $\pm 12$<br>$\pm 10$ | $\pm 14$<br>$\pm 13$ | —    | V               |
| Input Common-Mode Voltage Range  | $V_{ICR}$ | $\pm 8.0$            | $\pm 10$             | —    | V               |
| Common Mode Rejection Ratio<br>( $R_S \leq 10\text{ k}\Omega$ )  | $CMRR$    | 65                   | 90                   | —    | dB              |
| Supply Voltage Rejection Ratio<br>( $R_S \leq 10\text{ k}\Omega$ )   | $PSRR$    | —                    | 25                   | 200  | $\mu\text{V/V}$ |
| Transient Response<br>See Figure 8   | $t_{TLH}$ | —                    | 0.3                  | —    | $\mu\text{s}$   |
| Rise Time  | $t_{OS}$  | —                    | 10                   | —    | %               |
| Overshoot  |           |                      |                      |      |                 |

**ELECTRICAL CHARACTERISTICS** (unless otherwise specified,  $V_{CC} = +15\text{ V}$ ,  $V_{EE} = -15\text{ V}$ ,  $T_A = 0^\circ\text{C}$  to  $70^\circ\text{C}$ )

| Parameter  | Symbol   | MC1709C |     |     | Unit          |
|--|----------|---------|-----|-----|---------------|
|  |          | Min     | Typ | Max |               |
| Input Offset Voltage<br>( $R_S \leq 10\text{ k}\Omega$ , $9.0\text{ V} \leq V_{CC} \leq 15\text{ V}$ , $-9.0\text{ V} \geq V_{EE} \geq -15\text{ V}$ ) | $V_{IO}$ | —       | —   | 10  | mV            |
| Input Offset Current   | $I_{IO}$ | —       | —   | 750 | nA            |
| Input Bias Current   | $I_{IB}$ | —       | —   | 2.0 | $\mu\text{A}$ |
| Large Signal Voltage Gain<br>( $R_L \geq 2.0\text{ k}\Omega$ , $V_O = \pm 10\text{ V}$ )   | $A_V$    | 12      | —   | —   | V/mV          |
| Input Resistance   | $r_i$    | 35      | —   | —   | k $\Omega$    |

## TYPICAL CHARACTERISTICS

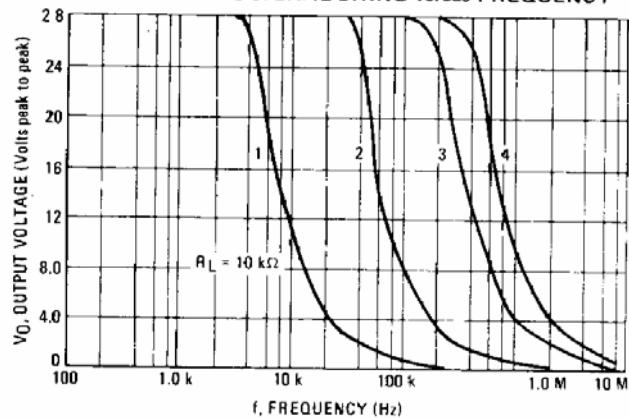
**FIGURE 2 – TEST CIRCUIT**  
( $V_{CC} = +15\text{ Vdc}$ ,  $V_{EE} = -15\text{ Vdc}$ ,  $T_A = +25^\circ\text{C}$ )



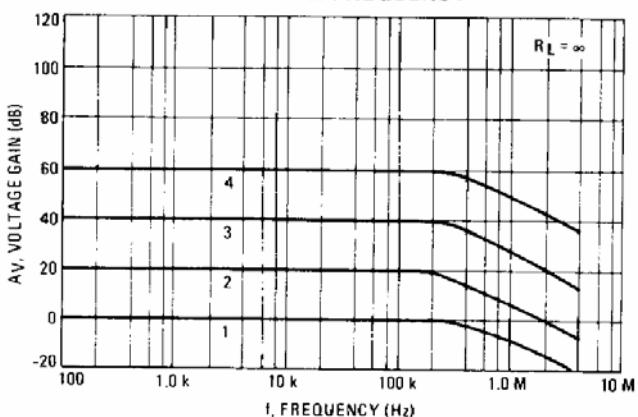
| Fig.<br>No. | Curve No. | Test Conditions |               |               |                  |                  |
|-------------|-----------|-----------------|---------------|---------------|------------------|------------------|
|             |           | $R_1(\Omega)$   | $R_2(\Omega)$ | $R_3(\Omega)$ | $C_1(\text{pF})$ | $C_2(\text{pF})$ |
| 3           | 1         | 10 k            | 10 k          | 1.5 k         | 5.0 k            | 200              |
|             | 2         | 10 k            | 100 k         | 1.5 k         | 500              | 20               |
|             | 3         | 10 k            | 1.0 M         | 1.5 k         | 100              | 3.0              |
|             | 4         | 1.0 k           | 1.0 M         | 0             | 10               | 3.0              |
| 4           | 1         | 1.0 k           | 1.0 M         | 0             | 10               | 3.0              |
|             | 2         | 10 k            | 1.0 M         | 1.5 k         | 100              | 3.0              |
|             | 3         | 10 k            | 100 k         | 1.5 k         | 500              | 20               |
|             | 4         | 10 k            | 10 k          | 1.5 k         | 5.0 k            | 200              |
| 5           | 1         | 0               | $\infty$      | 1.5 k         | 5.0 k            | 200              |
|             | 2         | 0               | $\infty$      | 1.5 k         | 500              | 20               |
|             | 3         | 0               | $\infty$      | 1.5 k         | 100              | 3.0              |
|             | 4         | 0               | $\infty$      | 0             | 10               | 3.0              |

## MC1709, MC1709A, MC1709C

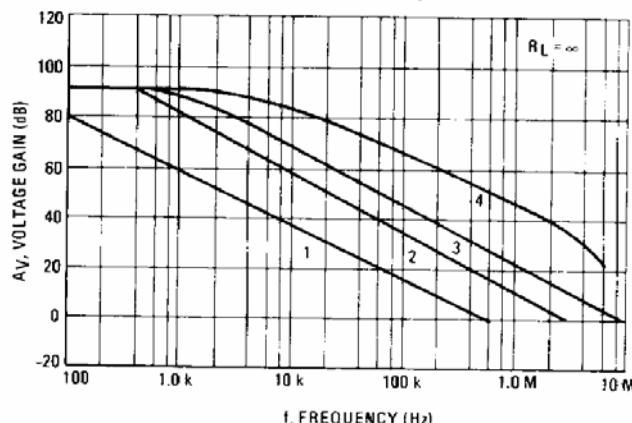
**FIGURE 3 – LARGE SIGNAL SWING versus FREQUENCY**



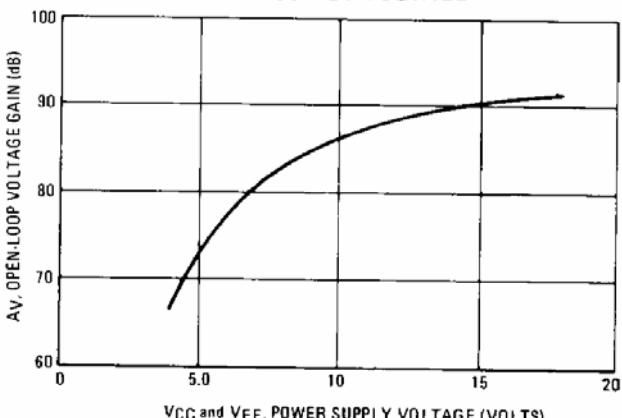
**FIGURE 4 – CLOSED LOOP VOLTAGE GAIN versus FREQUENCY**



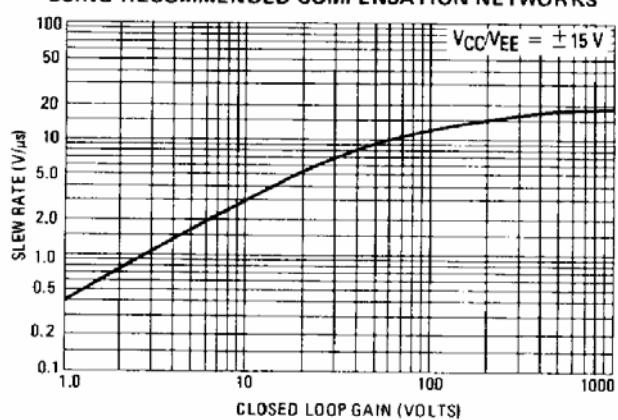
**FIGURE 5 – OPEN LOOP VOLTAGE GAIN versus FREQUENCY**



**FIGURE 6 – VOLTAGE GAIN versus POWER SUPPLY VOLTAGE**



**FIGURE 7 – SLEW RATE versus CLOSED LOOP GAIN USING RECOMMENDED COMPENSATION NETWORKS**



**FIGURE 8 – TRANSIENT RESPONSE TEST CIRCUIT**

